



## Low-Voltage Single SPDT Analog Switch

#### **DESCRIPTION**

The DG2002 is a single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed ( $t_{ON}$ : 8 ns,  $t_{OFF}$ : 6 ns), low on-resistance ( $r_{DS(on)}$ : 7  $\Omega$ ) and small physical size (SC70), the DG2002 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2002 is built on Vishay Siliconix's low voltage JI2 process. An epitaxial layer prevents latchup. Break-before make is guaranteed for DG2002.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

#### **FEATURES**

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance  $r_{DS(on)}$ : 7  $\Omega$
- Fast switching t<sub>ON</sub>: 8 ns, t<sub>OFF</sub>: 6 ns
- Low charge injection Q<sub>INJ</sub>: 5 pC
- Low power consumption
- TTL/CMOS compatible
- 6-pin SC70 package

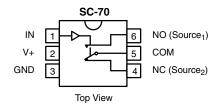
#### **BENEFITS**

- · Reduced power consumption
- Simple logic interface
- High accuracy
- · Reduce board space

#### **APPLICATIONS**

- · Cellular phones
- · Communication systems
- · Portable test equipment
- · Battery operated systems
- · Sample and hold circuits

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



Device Marking: E2xx

TRUTH TABLE						
Logic	NC	NO				
0	ON	OFF				
1	OFF	ON				

ORDERING INFORMATION						
Temp Range	Package	Part Number				
- 40 to 85 °C	SC70-6	DG2002DL-T1 DG2002DL-T1-E3				

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply.



ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Referenced V+ to GND		- 0.3 to +6	V			
IN, COM, NC, NO <sup>a</sup>		- 0.3 to (V+ + 0.3)	7 v			
Continuous Current (Any Terminal)		± 50	mA			
Peak Current (Pulsed at 1 ms, 10 % of	luty cycle)	± 200				
Storage Temperature		- 65 to + 150	°C			
Power Dissipation (Packages) <sup>b</sup>	Power Dissipation (Packages) <sup>b</sup> 6-Pin SC70 <sup>c</sup>		mW			

#### Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC Board.
- c. Derate 3.1 mW/°C above 70 °C.

SPECIFICATIONS V	+ = 2.0 V						
		Test Conditions Unless Otherwise Specified V+ = 2.0 V, ± 10 %		<b>Limits</b> - 40 to 85 °C			-
Parameter	Symbol	$V_{IN} = 0.4 \text{ or } 1.6 \text{ V}^{e}$	Temp <sup>a</sup>	Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	Unit
Analog Switch			1				
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC} V_{COM}$		Full	0		V+	V
On-Resistance	r <sub>ON</sub>	$V+ = 1.8 \text{ V}, V_{COM} = 1.0 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room Full <sup>d</sup>		38 39.3	46.1 47.1	Ω
r <sub>ON</sub> Flatness <sup>d</sup>	r <sub>ON</sub> Flatness	$V+ = 1.8 \text{ V}, V_{COM} = 0 \text{ to } V+, I_{NO}, I_{NC} = 10 \text{ mA}$ Roo			21		52
Cuitab Off Lookaga Current	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 2.2 V	Room Full <sup>d</sup>	- 250 - 3.0		250 3.0	pA nA
Switch Off Leakage Current <sup>†</sup>	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC} = 0.5 \text{ V}/1.5 \text{ V}$ , $V_{COM} = 1.5 \text{ V}/0.5 \text{ V}$	Room Full <sup>d</sup>	- 250 - 3.0		250 3.0	pA nA
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	$V+ = 2.2 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.5 \text{ V}/1.5 \text{ V}$	Room Full <sup>d</sup>	- 250 - 3.0		250 3.0	pA nA
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.6			V
Input Low Voltage	V <sub>INL</sub>		Full			0.4	v
Input Capacitance <sup>d</sup>	C <sub>in</sub>		Full		3		pF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 or V+	Full	- 1		1	μΑ
Dynamic Characteristics							•
Turn-On Time	t <sub>ON</sub>	VV 45 V.D	Room Full <sup>d</sup>		22	31 32	
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF Figures 1 and 2	Room Full <sup>d</sup>		10	17 18	ns
Break-Before-Make Time	t <sub>d</sub>		Room	1	12		
Charge Injection <sup>d</sup>	$Q_{INJ}$	$C_L$ = 1 nF, $V_{GEN}$ = 0 V, $R_{GEN}$ = 0 $\Omega$ , Figure 3	Room		5	10	рC
Off-Isolation <sup>d</sup>	OIRR	$R_1 = 50 \Omega$ , $C_1 = 5 pF$ , $f = 1 MHz$	Room		- 67		40
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$n_L = 50 \text{ sz}, O_L = 5 \text{ pr}, I = 1 \text{ winz}$	Room		- 71		dB
NO, NC Off Capacitance <sup>d</sup>	$C_{NO(off)} \ C_{NC(off)}$	V <sub>IN</sub> = 0 or V+, f = 1 MHz Room			5		pF
Channel-On Capacitance <sup>d</sup>	C <sub>ON</sub>				29		'
Power Supply	<u>.                                      </u>				1	1	
Power Supply Range	V+			1.8		2.2	V
Power Supply Current <sup>d</sup>	l+	V <sub>IN</sub> = 0 or V+			0.01	1.0	μΑ
Power Consumption	Power Consumption P <sub>C</sub>					2.2	μW





		Test Conditions Unless Otherwise Specified $V+=3~V,~\pm 10~\%$		<b>Limits</b> - 40 to 85 °C				
Parameter	Symbol	$V_{IN} = 0.4 \text{ or } 2.0 \text{ V}^e$	Temp <sup>a</sup>	Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	Unit	
Analog Switch						l		
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC} \ V_{COM}$		Full	0		V+	V	
On-Resistance <sup>d</sup>	r <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{COM} = 1.5 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room Full		12.2 13	14.8 15.8	Ω	
r <sub>ON</sub> Flatness <sup>d</sup>	r <sub>ON</sub> Flatness	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to } V+, I_{NO}, I_{NC} = 10 \text{ mA}$	Room		5		52	
Switch Off Leakage Current <sup>f</sup>	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 3.3 V	Room Full	- 500 - 4.0		500 4.0	pA nA	
Switch On Leakage Current	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC} = 1 \text{ V/3 V}$ , $V_{COM} = 3 \text{ V/1 V}$	Room Full	- 500 - 4.0		500 4.0	pA nA	
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V/3 V}$ Room Full		- 500 - 4.0		500 4.0	pA nA	
Digital Control			•					
Input High Voltage	V <sub>INH</sub>		Full	ıll 2			V	
Input Low Voltage	V <sub>INL</sub>		Full			0.4	V	
Input Capacitance <sup>d</sup>	C <sub>in</sub>		Full		3		pF	
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 or V+	Full	- 1		1	μΑ	
Dynamic Characteristics			•					
Turn-On Time <sup>d</sup>	t <sub>ON</sub>	V 24V 20VD 2000 C 25 pC	Room Full		12	21 22		
Turn-Off Time <sup>d</sup>	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC}$ = 2.0 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF Figures 1 and 2	Room Full		7	14 15	ns	
Break-Before-Make Time <sup>d</sup>	t <sub>d</sub>		Room	1	6			
Charge Injection <sup>d</sup>	$Q_{INJ}$	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ $\Omega$ , Figure 3	Room		5	10	рC	
Off-Isolation <sup>d</sup>	OIRR	D 5000 5 5 1 1 MHz	Room		- 67		-10	
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 69		dB	
NO, NC Off Capacitance <sup>d</sup>	$C_{NO(off)} \ C_{NC(off)}$	V <sub>IN</sub> = 0 or V+, f = 1 MHz			5		pF	
Channel-On Capacitanced	C <sub>ON</sub>				29			
Power Supply	<u>.                                    </u>							
Power Supply Range	V+			2.7		3.3	V	
Power Supply Current	l+	I+ V <sub>IN</sub> = 0 or V+			0.01	1.0	μΑ	
Power Consumption P <sub>C</sub>						3.3	μW	



SPECIFICATIONS V+ = 5.0 V										
		Test Conditions Unless Otherwise Specified V+ = 5 V, ± 10 %		<b>Limits</b> - 40 to 85 °C			-			
Parameter	Symbol	V <sub>IN</sub> = 0.8 or 2.4 V <sup>e</sup>		Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	Unit			
Analog Switch										
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC,} V_{COM}$		Full	0		V+	V			
On-Resistance	r <sub>ON</sub>	V+ = 4.5 V, V <sub>COM</sub> = 3 V, I <sub>NO</sub> , I <sub>NC</sub> = 10 mA	Room Full		6.4 7.4	7.8 8.8	Ω			
r <sub>ON</sub> Flatness <sup>d</sup>	r <sub>ON</sub> Flatness	$V+ = 4.5 \text{ V}, V_{COM} = 0 \text{ to } V+, I_{NO}, I_{NC} = 10 \text{ mA}$	Room		3		1 12			
Switch Off Leakage Current	I <sub>NO(off),</sub> I <sub>NC(off)</sub>	V+ = 5.5 V	Room Full	- 1.0 - 4.0		1.0 4.0				
Switch Off Leakage Current	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC} = 1 \text{ V}/4.5 \text{ V}$ , $V_{COM} = 4.5 \text{ V}/1 \text{ V}$	Room Full	- 1.0 - 4.0		1.0 4.0	nA			
Channel-On Leakage Current	I <sub>COM(on)</sub>	V+ = 5.5 V, V+ = 5.5 V $V_{NO}, V_{NC} = V_{COM} = 1 V/4.5 V$	Room Full	- 1.0 - 4.0		1.0 4.0				
Digital Control			•		I.					
Input High Voltage	$V_{INH}$		Full	2.4			.,			
Input Low Voltage	V <sub>INL</sub>		Full			0.8	V			
Input Capacitance	C <sub>in</sub>		Full		3		pF			
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 or V+	Full	- 1		1	μΑ			
Dynamic Characteristics					<u> </u>	l				
Turn-On Time <sup>d</sup>	t <sub>ON</sub>	VV 0.V.B 000.0.0 05 5	Room Full		8	15 16				
Turn-Off Time <sup>d</sup>	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC}$ = 3 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF Figures 1 and 2	Room Full		6	13 14	ns			
Break-Before-Make Time <sup>d</sup>	t <sub>d</sub>		Room	1	4					
Charge Injection <sup>d</sup>	$Q_{INJ}$	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega, \text{ Figure 3}$	Room		5	10	рС			
Off-Isolation <sup>d</sup>	OIRR	D 5000 5 5 6 4 MHz	Room		- 69					
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 69		dB			
Source-Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub> , C <sub>NC(off)</sub>	V <sub>IN</sub> = 0 or V+, f = 1 MHz	Room		5		pF			
Channel-On Capacitance <sup>d</sup>	C <sub>ON</sub>	R			29		1			
Power Supply			<u> </u>			1				
Power Supply Range	V+			4.5		5.5	٧			
Power Supply Current	l+	V <sub>IN</sub> = 0 or V+			0.01	1.0	μΑ			
Power Consumption	$P_{C}$	VIN = O OI V+				5.5	μW			

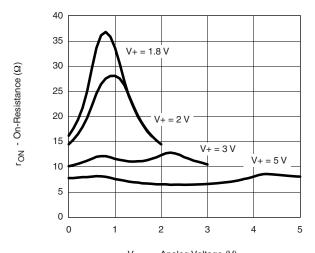
#### Notes:

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. Guaranteed by 5 V leakage testing, not production tested.

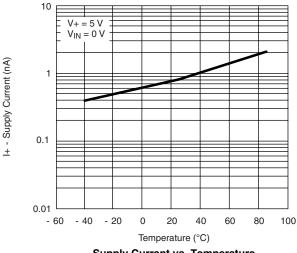
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



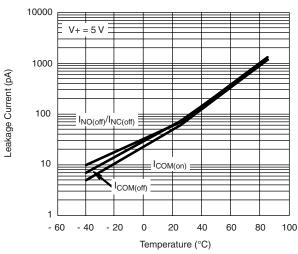
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



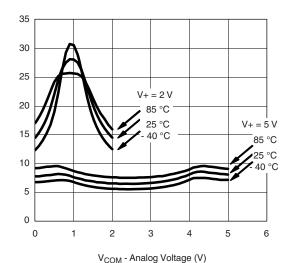
V<sub>COM</sub> - Analog Voltage (V) r<sub>ON</sub> vs. V<sub>COM</sub> and Supply Voltage



Supply Current vs. Temperature

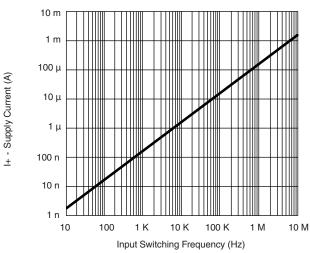


Leakage Current vs. Temperature

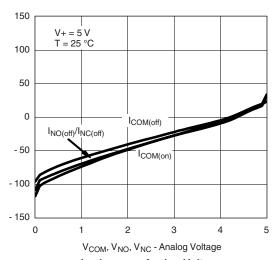


 $r_{\text{ON}}$  - On-Resistance ( $\Omega$ )

r<sub>ON</sub> vs. Analog Voltage and Temperature



**Supply Current vs. Input Switching Frequency** 

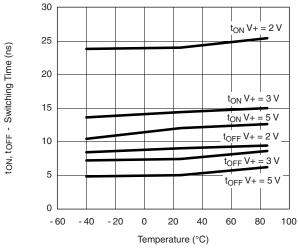


Leakage vs. Analog Voltage

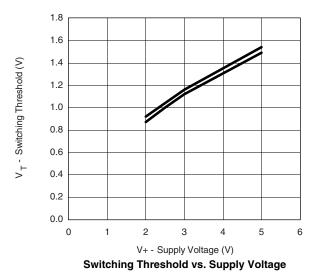
Leakage Current (pA)

# VISHAY

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

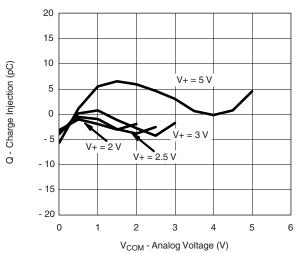


Switching Time vs. Temperature and Supply Voltage



0 LOSS - 10 - 20 Loss, OIRR, X<sub>TALK</sub> (dB) - 30 - 40 - 50 - 60 - 70  $R_L = 50 \Omega$ - 80 - 90 - 100 100 K 1 M 10 M 100 M 1 G Frequency (Hz)

Insertion Loss, Off -Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage



#### **TEST CIRCUITS**

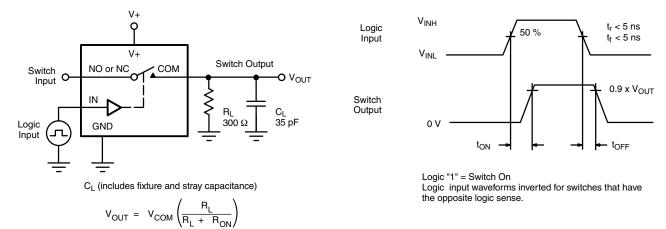


Figure 1. Switching Time

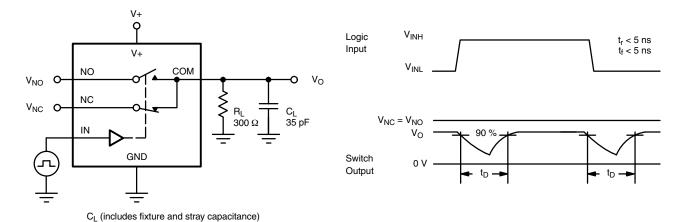


Figure 2. Break-Before-Make Interval

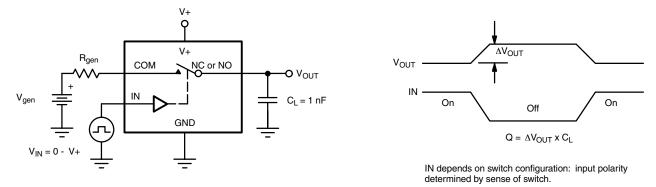


Figure 3. Charge Injection

#### **TEST CIRCUITS**

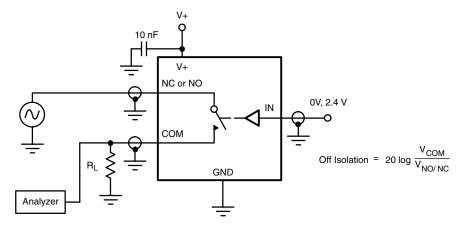


Figure 4. Off-Isolation

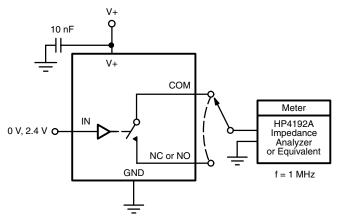
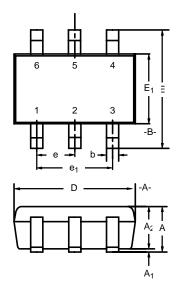


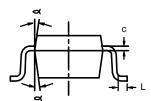
Figure 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71448.



#### SC-70: 6-LEADS





	MIL	LIMET	ERS	I	NCHE	S		
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.90	_	1.10	0.035	_	0.043		
$A_1$	_	-	0.10	-	_	0.004		
A <sub>2</sub>	0.80	_	1.00	0.031	_	0.039		
b	0.15	_	0.30	0.006	_	0.012		
С	0.10	_	0.25	0.004	_	0.010		
D	1.80	2.00	2.20	0.071	0.079	0.087		
Е	1.80	2.10	2.40	0.071	0.083	0.094		
E <sub>1</sub>	1.15	1.25	1.35	0.045	0.049	0.053		
е	0.65BSC			0.026BSC				
e <sub>1</sub>	1.20	1.30	1.40	0.047	0.051	0.055		
L	0.10	0.20	0.30	0.004	0.008	0.012		
4		7°Nom	Nom 7°Nom					
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